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The band structure of MgB_2 with different lattice constants

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Abstract

We report a detailed study of the electronic structure of the MgB_2 with different lattice constants by using the full-potential linearized augmented plane wave(FPLAPW) method. It is found that the lattice parameters have great effect on the σ band of Boron. Our results indicate that increasing the lattice constant along the c axis will increase the density of states(DOS) at the Fermi level, shift the σ band upward, and increase the hole number in the σ band. So, the superconducting transition temperature T_c will be raised correspondingly. Changing the lattice constant along a axis has the opposite effect to that of the c axis. Our result is in agreement with experiment. A possible way of searching for higher T_c superconductor has been indicated, i.e., making MgB_2 to have longer c axis and shorter *a, b* axis by doping.

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The discovery of superconductivity in magnesium diboride (MgB_2) [1,2] has stimulated world wide excitement. The superconducting transition temperature for MgB_2 ($T_C \approx 39$ K) exceeds by almost two times the record values of T_C for conventional $B1$- and $A15$-type intermetallic superconductors (SC) [3], which is by far the highest if we exclude copper oxides and C_{60} based materials. As distinct from the high-temperature superconductor, MgB_2 has an exclusively simple composition and crystal structure [4]. The B isotope shift of T_c reported by Bud'ko [5] and most other early experimental data[6] suggests conventional BCS strong-coupling s-wave electron-phonon (EP) pairing.

Band structure calculations show that the compound is not only quite ionic with a reasonable DOS, but also has strong covalent B-B bonding (the bonding-antibonding splitting due to in-plane B-B hopping is about 6 eV) and thus exhibits strong electron-phonon interactions[7, 8, 9]. Mg s-states are pushed up by the B p_z orbitals and fully donate their electrons to the boron-derived conduction bands. Hirsch used a hole-superconductivity model to explain the high temperature superconductivity in MgB_2 as driven by undressing of hole carriers in the planar boron $p_{x,y}$ orbitals in the negatively charged B^- planes [10]. The model by Hirsch predicts a positive pressure effect on T_c. However, high pressure studies show negative pressure coefficient of T_c[11, 12]. Based on an estimate of phonon frequencies and band structure calculations, Kortus et al[8] explain the superconductivity in MgB_2 as a result of strong electron-phonon coupling and An and Pickett[7] attributed it to the behavior of $p_{x,y}$-band holes in negatively charged boron planes. Many authors[7-9] emphasize the significant role of metallic B states in the appearance of superconductivity. According to the McMillan formula for T_C[13], the high transition temperature is probably due to a high density of states at the Fermi level, $N(E_F)$, high averaged electron-ion matrix elements, as well as high phonon frequencies, which increase for light elements and depend on $B-B$ and $M-B$ bonding.

Past experience said that T_c should be strongly affected by doping or changing the lattice constants. Some experiments concerning substitutions on the Mg site have been done[14, 15]. Substitution of Al leads, apart from doping with electrons, to a compression of the structure

due to the difference in ionic radius between Al and Mg. The compression is anisotropic and an Al content of x=0.1 leads to a structural instability. The rate of compression along the c axis is about twice as much as along the a axis[14]. Both hole doping by substitution of Li^{+}[15], and electron doping by substitution of Al^{3+}[14] for Mg^{2+} led to a decrease of T_c. In fact, Al doping will destroy bulk superconductivity when the Al content x is larger than 0.3[14]. There are also many experiments concerning Boron sublattice doping[16]. The lattice parameter a decreases almost linearly with increasing carbon content x, while the c parameter remains unchanged, indicating that carbon is exclusively substituted in the Boron honeycomb layer without affecting the interlayer interactions. T_c also decreases about linearly as a function of the carbon concentration. A recent experiment had also found BiB_2 not to be a superconductor[17]. BiB_2 and MgB_2 are isostructural, and their valence electron number is the same. So, the basic change is due to structural factors, i.e. lattice parameter, a, and interatomic distance, c/a. Recently, high pressure studies show that T_c will decrease with increasing pressure[11, 12]. Compression will decrease both lattice constant a and c, but it is not yet know which one of them is responsible for decreasing T_c. So, it is very interesting to investigate the Boron band structure, especially the π and σ band, as a function of lattice constants a and c.

We have used the highly accurate all-electron full-potential linear augmented plane wave method[18, 19]. The standard local density approximation to the electron exchange-correlation potential was used together with the generalized gradient corrections of Perdew[20]. The muffin-tin sphere radii (R) of 2.00 a.u. and 1.50 a.u. were chosen for the Mg and B atoms, respectively, with a cutoff RK_{max}=8.0.

MgB_2 is isomorphous with AlB_2[4]; the lattice constants of the hexagonal unit cell are a_0=3.0834 and c_0=3.5213 $\mathring{A}$. From the existing experiments we can see that high hydrostatic pressure has an anisotropic influence along a and c. The compression along the c axis is 64% stronger than along the a axis, which is in line with the weaker Mg-B bond[21]. Thermal compression along the c axis is about twice the one along the a axis. So, we fix a=3.0834$\mathring{A}$, and vary lattice constant c. The total energy-vs-c relation is shown in Fig.1. It can be seen

that c=c_0=3.5213 $\mathring{A}$ with the lowest total energy agrees with the experimental result.

The band structure of MgB_2 is shown in Fig.2. For convenience, we set E_f=0. From it we can see that there are two kinds of bands: the σ and π band. Both of them are contributed by Boron. The σ band along Γ-A is double degenerate. Change of lattice constant will not change the symmetry, and so will not change its character. We found when c=1.4c_0, the σ band has a very small dispersion along Γ-A. But it will increase with decreasing c. Thus increasing c will strengthen the 2D character of the σ band, and if c approaches ∞, MgB_2 becomes an ideal 2D B_2 layer. Another evident change is that the σ band will shift upward with respect to the E_f when we increase c. For c=0.8c_0, the σ band is below the Fermi energy, and the σ bonding state would be completely filled. For c=0.9c_0, the σ band will cross the Fermi energy at the Γ point. With increasing c, the σ band will shift upward, and so will have more holes. On the other hand, increasing c will decrease the hopping coefficient $t_{pp\sigma}$ in Kortus's TB model[8] for the π band, and will cause the π band dispersion along Γ-A decrease. Comparing with E_f, increasing c will decrease the position of bonding π band at M and Γ point, and will raise the position of bonding π band at A and L point.

We have also studied the effect of lattice constant a on the electronic structure, and found it to be opposite to c. With decreasing a, both bonding and antibonding σ band will move upward with respect to E_f, and the splitting between bonding and antibonding σ band will increase. When c=0.8c_0 and a=a_0, the bonding σ band is below the Fermi energy. Fixing c and decreasing the a, the bonding σ band will move upward. From Fig.2(d), we can see that, when c=0.8c_0 and a= 0.9a_0, its σ band lies higher than it in Fig.2(a), and there are holes in the bonding σ band. The increase of splitting between bonding and antibonding σ band is due to increase of the hopping coefficient with decreasing a. The possible reason why σ band moves upward is electrostatic effect. Being different from σ band, the bonding π band will move downward with respect to the E_f when a decreases. Compression will decrease both the a and c. But σ bond of B-B is much stronger than the Mg-B bond, so, it is natural to expect that compression will mainly cause the decrease of c[21]. Thus, we

can conclude that compression will shift the σ band downward and decrease the number of holes in the σ band.

We have also studied the relationship between the density of states at the Fermi level(N_f) and the lattice constants, which is shown in Fig.3. It is found that N_f will increase with increasing of the lattice constant c, which is in agreement with other theoretical results[22, 23]. Many theories and experiments show that the MgB_2 is a BCS-like superconductor. So the electron-phonon coupling constant λ, which enters the BCS equation, is very important[13], and is proportional to N_f. Since N_f will decrease for smaller c, T_c will be decreased, which is in agreement with experiments[11, 12]. The states at the Fermi level, responsible for superconductivity, show two different orbital characters: $p-\sigma$ bonding (column–like FS around $\Gamma - A$) and p_z, which has π-bonding and antibonding characters on the basal and on the top ($k_z = \pi/c$) planes, respectively. Which one of them is the most important for the superconductivity is not yet known. In order to answer this question, we calculate the partial DOS of π and σ band of MgB_2 with different lattice constants c. We find that with a larger c, $N_f(\sigma)$ will increase, whereas $N_f(\pi)$ will decrease. Here, the $N_f(\sigma)$ ($N_f(\pi)$) means the density of σ (π) state at Fermi energy. So, we can say that the σ band of Boron plays a more important role for superconductivity than the π band. The p_σ and p_π bands move with respect to each other with increasing c, thus inducing charge transfer between these two bands. It is the reason why the $N_f(\sigma)$ has an opposite trend to $N_f(\pi)$. Our result is in agreement with Goncharov and Bud'ko et al.,'s result[24].

In summary, we calculated the electronic structure of MgB_2 for different lattice constants. Our results show that increasing lattice constant c will increase the DOS at the Fermi level, shift the σ band upward, and thus increase the hole number in the σ band. Decreasing c will lower the T_c. The effect of changing a is opposite to c. For constant c, a shorter a will raise T_c. The main influence of compression is to decrease c, and thus will decrease the T_c, which is in agreement with the experiments[11, 12]. A search for a higher T_c superconductor by doping MgB_2, would require a longer lattice constant c and shorter *a, b*. A possible way would be a suitable substrate, which forces MgB_2 film to have longer c but shorter *a, b*.

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REFERENCES

[1] R. J. Cava; Nature **410**, 23 (2001).

[2] J. Nagamatsu, N. Nakagawa, T. Muranaka, Y. Zenitani and J. Akimitsu; Nature **410**, 63 (2001).

[3] S. V. Vonsovsky, Y. A. Izumov, and E. Z. Kurmaev; Superconductivity of Transition Metals, Alloys and Compounds, Springer, Berlin, (1982).

[4] M. E. Jones and R. E. Marsh; J. Am. Chem. Soc. **76**, 1434 (1954).

[5] S. L. Bud'ko, G. Lapertot, C. Petrovic, C. E. Cunningham, N. Anderson, and P. C. Canfield, Phys. Rev. Lett. **86**, 1877 (2001).

[6] D. K. Finnemore, J. E. Ostenson, S. L. Bud'ko, G. Lapertot, and P. C. Canfield , Phys. Rev. Lett. **86**, 2420 (2001); G. Rubio-Bollinger, H. Suderow, and S. Vieira , Phys. Rev. Lett. **86**, 5582 (2001); B. Lorenz, R. L. Meng, C. W. Chu, cond-mat/0102264; P. C. Canfield, D. K. Finnemore, S. L. Bud'ko, J. E. Ostenson, G. Lapertot, C. E. Cunningham, and C. Petrovic , Phys. Rev. Lett. **86**, 2423 (2001); A. Sharoni, I. Felner, and O. Millo Phys. Rev. B **63**, 220508R (2001); H. Kotegawa, K. Ishida, Y. Kitaoka, T. Muranaka, J. Akimitsu, cond-mat/0102334.

[7] J. M. An and W. E. Pickett; Phys. Rev. Lett. **86**, 4366 (2001).

[8] J. Kortus, I. I. Mazin, K. D. Belashenko, V. P. Antropov and L. L. Boyer, Phys. Rev. Lett. **86**, 4656 (2001).

[9] K. D. Belashenko, M. van Schilfgaarde and V. P. Antropov, cond-mat/0102290 (2001); T. Yildirim, O. Gulseren, J. W. Lynn, C. M. Brown, T. J. Udovic, H. Z. Qing, N. Rogado, K.A. Regan, M.A. Hayward, J.S. Slusky, T. He, M.K. Haas, P. Khalifah, K. Inumaru, R.J. Cava, Phys. Rev. Lett. **87**, 037001 (2001).

[10] J. E. Hirsch, Phys. Lett. A **282**, 392 (2001).

[11] B. Lorenz, R. L. Meng and C. W. Chu; Phys. Rev. B **64**, 012507 (2001).

[12] M. Monteverde, M. Nunez-Regueiro, N. Rogado, K. A. Regan, M. A. Hayward, T. He, S. M. Loureiro, and R. J. Cava, Science **292**, 75 (2001).

[13] W. L. McMillan, Phys. Rev. **167**, 331 (1968).

[14] J. S. Slusky, N. Rogado, K. A. Regan, M. A. Hayward, P. Khalifah, T. He, Nature **410**, 343 (2001).

[15] Y. G. Zhao, X. P. Zhang, P. T. Qiao, H. T. Zhang, S. L. Jia, B. S. Cao M. H. Zhu, Z. H. Han, X. L. Wang, B. L. Gu, cond-mat/0103077 (2001).

[16] S. Zhang, J. Zhang, T. Zhao, C. Rong, B. Shen, Z. Cheng, cond-mat/0103203; T. Takenobu, T. Ito, Dam H. Chi, K. Prassides, Y. Iwasa, cond-mat/0103241; J. S. Ahn, and E. J. Choi, cond-mat/0103169 (2001).

[17] I. Felner, cond-mat/0102508 (2001).

[18] D. J. Singh, *Planewaves, Pseudopotentials, and the LAPW Method* (Kluwer Academic, Boston, 1994).

[19] P. Blaha, K. Schwarz, and J. Luitz, WIEN97, Vienna University of Technology, 1997; P. Blaha, K. Schwarz, P. Sorantin, and S. B. Trickey, Comput. Phys. Commun. **59**, 399 (1990).

[20] J. P. Perdew, J. A. Chevary, S. H. Vosko, K. A. Jackson, M. R. Pederson, D. J. Singh, and C. Fiolhais , Phys. Rev. B **46**, 6671 (1992); J. P. Perdew, K. Burke, and M. Ernzerhof, Phys. Rev. Lett. **77**, 3865 (1996).

[21] J. D. Jorgensen, D. G. Hinks, and S. Short, Phys. Rev. B **63**, 224522 (2001)

[22] I. Loa and K. Syassen, Solid State Commun. **118**, 279 (2001).

[23] J. B. Neaton and A. Perali, cond-mat/0104098 (2001).

[24] A. F. Goncharov et al., cond-mat/0106258 (2001).

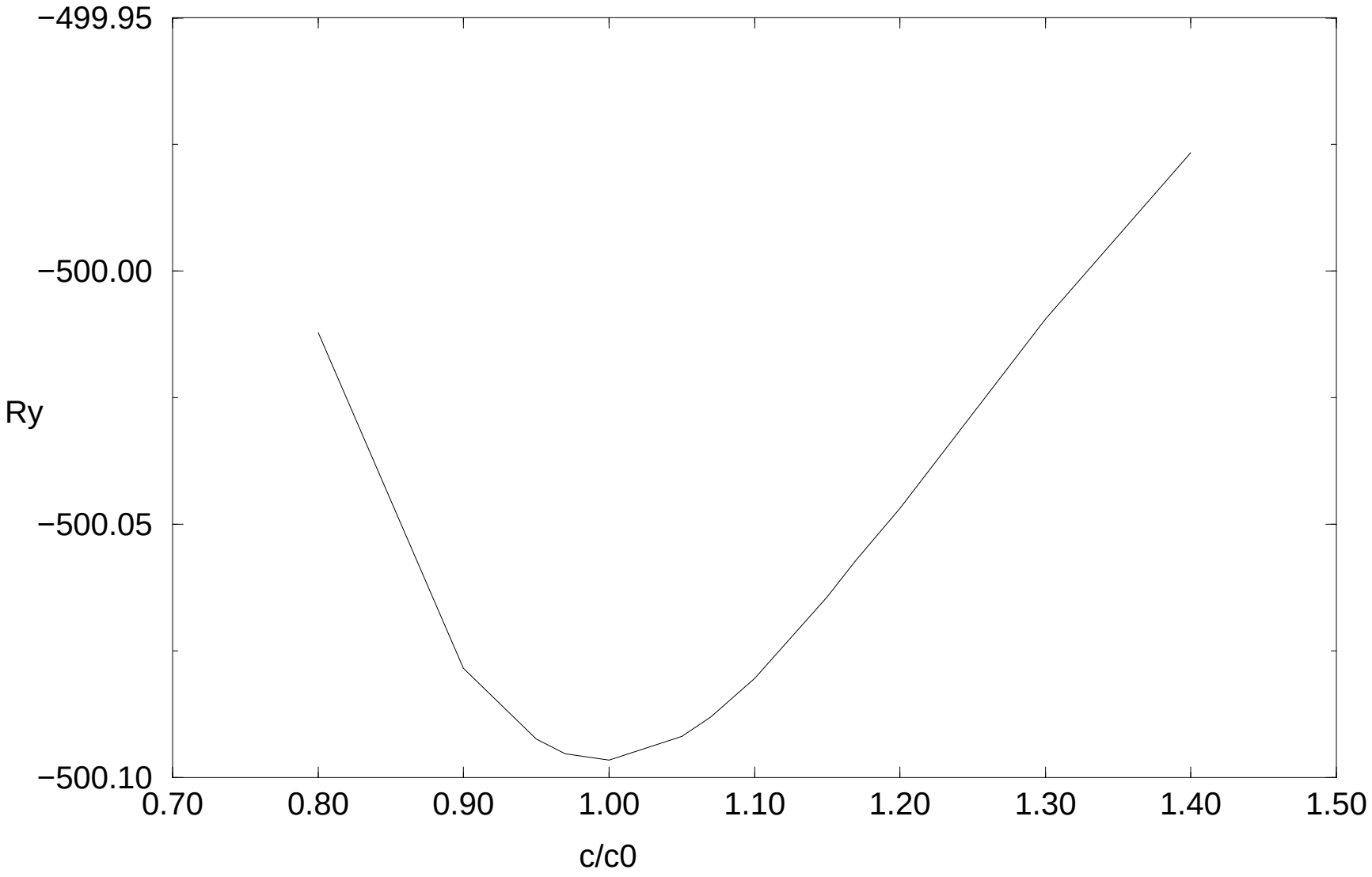
Figure Captions

Figure 1 The total energy of MgB_2 as a function of lattice parameter c/c_0. c_0= 3.5213$\mathring{A}$.

Figure 2 The band structure of MgB_2 with different lattice constants. The circles represent the Boron σ band. a_0= 3.0834$\mathring{A}$, c_0= 3.5213$\mathring{A}$. (a) a=a_0, c=0.8c_0; (b) a=a_0, c=c_0; (c) a=a_0, c=1.4c_0; (d) a=0.9a_0, c=0.8c_0.

Figure 3 Density of states near E_f for MgB_2 with different lattice constants, c/c_0=0.8, 1.0 and 1.4. Fermi level is set at the zero.

Fig1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1.40
1.50
c/c0

Fig2a

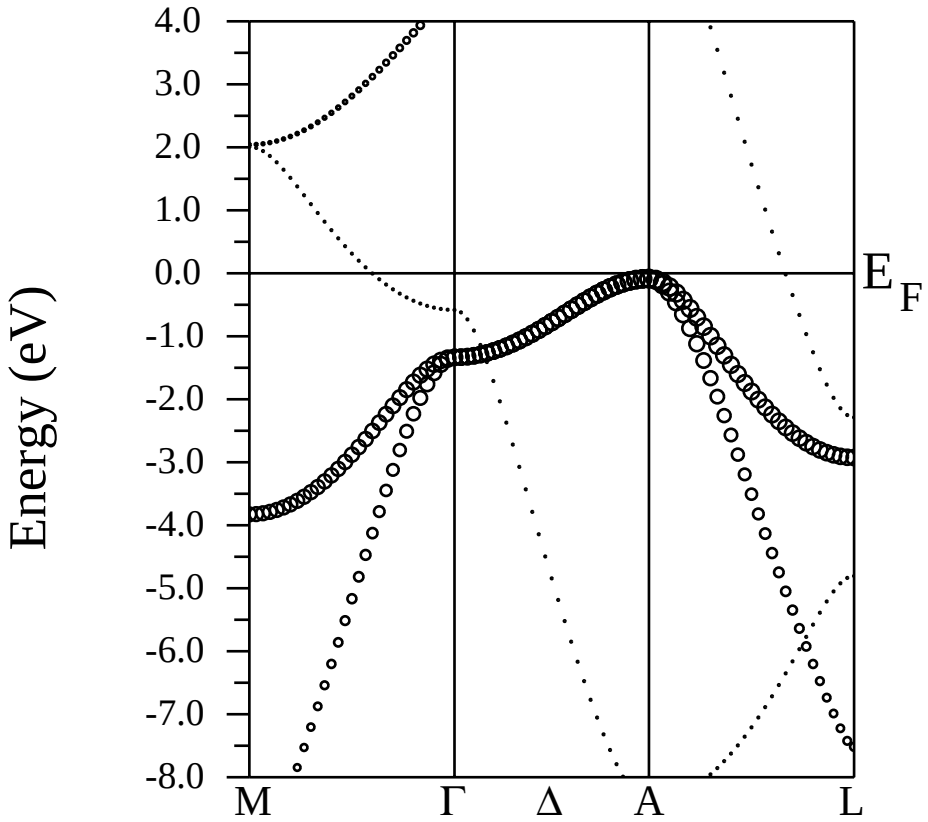

Fig2b

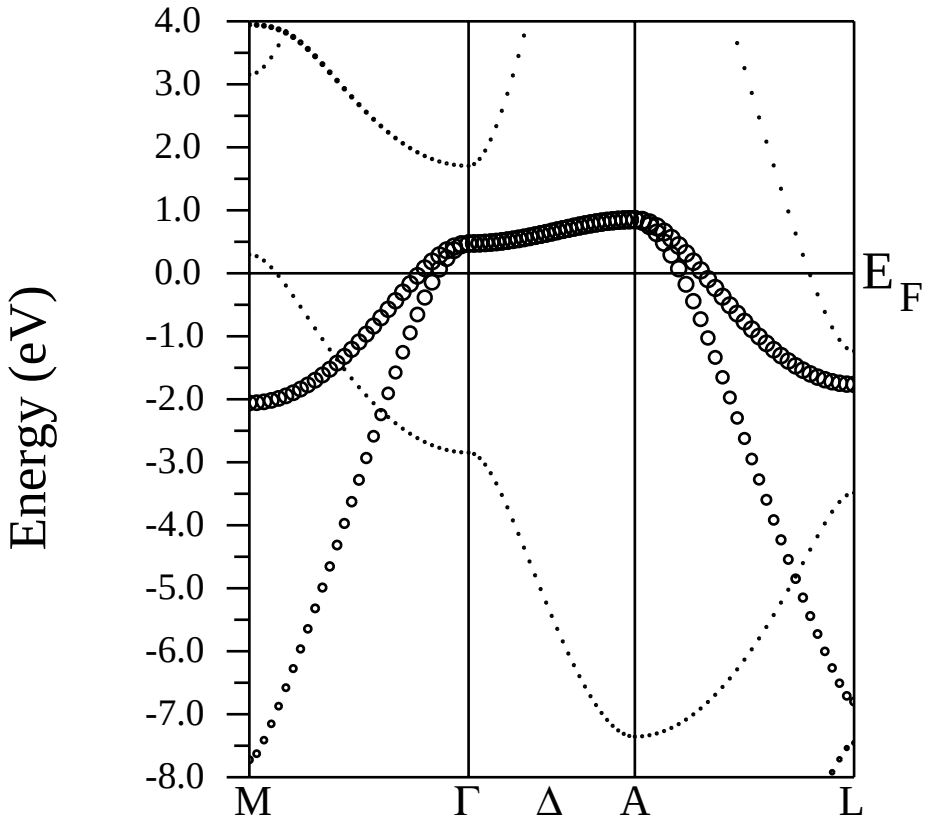

Fig2c

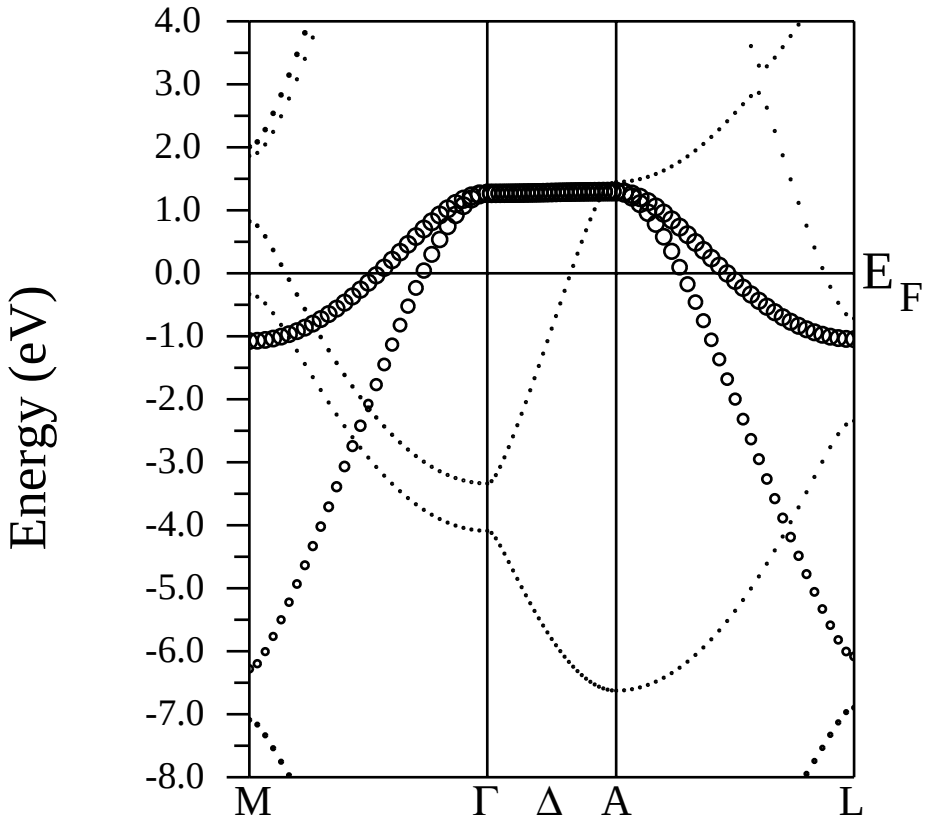

Fig2d

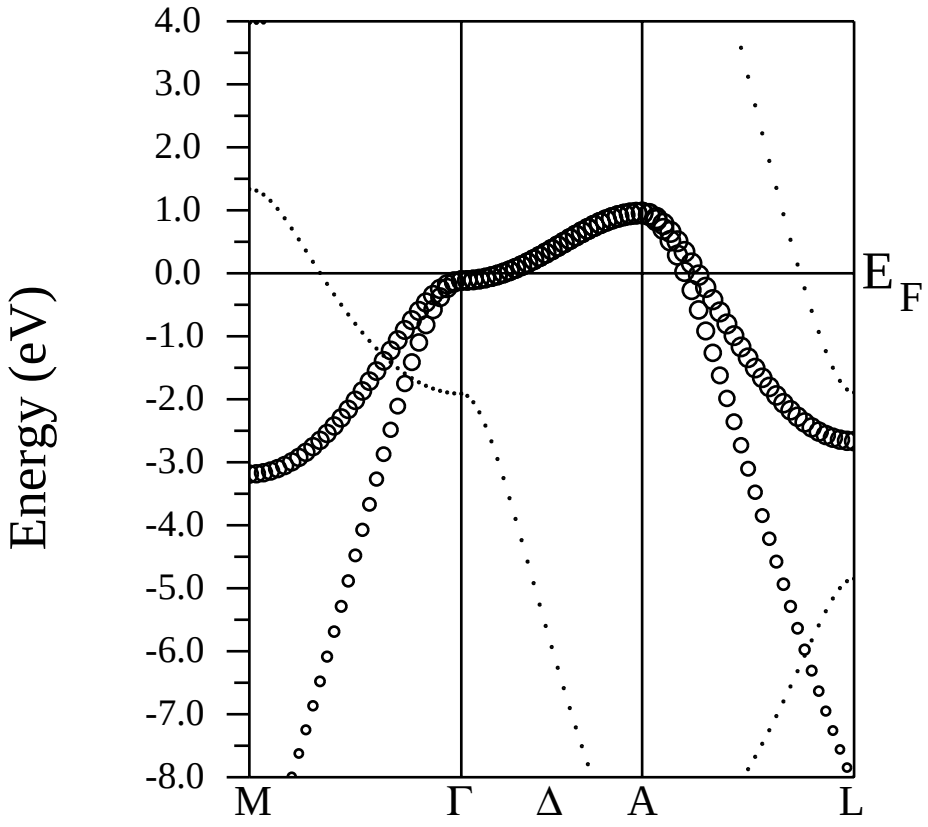

Fig3